

Notice of References Cited

Application/Control No.

09/663,340

Applicant(s)/Patent Under

Reexamination

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Examiner

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Art Unit

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U.S. PATENT DOCUMENTS

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Name	Classification
	A	US-6,111,283-Derwent	08-2000	Yang et al.	257/306
	B	US-			
	C	US-			
	D	US-			
	E	US-			
	F	US-			
	G	US-			
	H	US-			
	I	US-			
	J	US-			
	K	US-			
	L	US-			
	M	US-			

FOREIGN PATENT DOCUMENTS

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Country	Name	Classification
	N					
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	Q					
	R					
	S					
	T					

NON-PATENT DOCUMENTS

*		Include as applicable: Author, Title Date, Publisher, Edition or Volume, Pertinent Pages)
	U	M. Kato et al, "A 0.4 micrometer-squared Self-Aligned Contactless Memory Cell Technology Suitable for 256-Mbit Flash Memories", Electron Dev. Mtg. '94, Techn. Digest pp. 921-3, 11-14 Dec.'94, San Francisco, USA (ISBN: 0-7803-2111-1)
	V	
	W	
	X	

*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).)

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